

# MMUN2211LT1 Series

Preferred Devices

## Bias Resistor Transistor

### NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-23 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space and Component Count
- The SOT-23 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Available in 8 mm embossed tape and reel. Use the Device Number to order the 7 inch/3000 unit reel. Replace "T1" with "T3" in the Device Number to order the 13 inch/10,000 unit reel.

#### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	Vdc
Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current	$I_C$	100	mAdc
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 1) Derate above $25^\circ\text{C}$	$P_D$	200 1.6	mW mW/ $^\circ\text{C}$

#### DEVICE MARKING AND RESISTOR VALUES

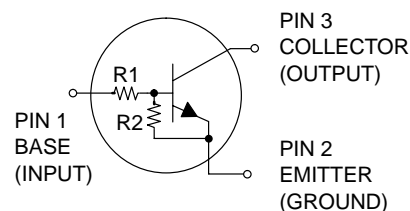
Device	Marking	R1(K)	R2(K)
MMUN2211LT1	A8A	10	10
MMUN2212LT1	A8B	22	22
MMUN2213LT1	A8C	47	47
MMUN2214LT1	A8D	10	47
MMUN2215LT1	A8E	10	$\infty$
MMUN2216LT1	A8F	4.7	$\infty$
MMUN2230LT1	A8G	1.0	1.0
MMUN2231LT1	A8H	2.2	2.2
MMUN2232LT1	A8J	4.7	4.7
MMUN2233LT1	A8K	4.7	47
MMUN2234LT1	A8L	22	47
MMUN2238LT1	A8R	2.2	$\infty$
MMUN2241LT1	A8U	100	$\infty$

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.

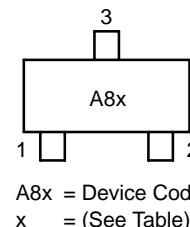
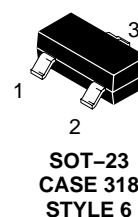


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#### MARKING DIAGRAM



#### ORDERING INFORMATION

Device	Package	Shipping†
MMUN2211LT1	SOT-23	3000/Tape & Reel
MMUN2212LT1	SOT-23	3000/Tape & Reel
MMUN2213LT1	SOT-23	3000/Tape & Reel
MMUN2214LT1	SOT-23	3000/Tape & Reel
MMUN2215LT1	SOT-23	3000/Tape & Reel
MMUN2216LT1	SOT-23	3000/Tape & Reel
MMUN2230LT1	SOT-23	3000/Tape & Reel
MMUN2231LT1	SOT-23	3000/Tape & Reel
MMUN2232LT1	SOT-23	3000/Tape & Reel
MMUN2233LT1	SOT-23	3000/Tape & Reel
MMUN2234LT1	SOT-23	3000/Tape & Reel
MMUN2238LT1	SOT-23	3000/Tape & Reel
MMUN2241LT1	SOT-23	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

# MMUN2211LT1 Series

## THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance – Junction-to-Ambient (surface mounted)	$R_{\theta JA}$	625	$^{\circ}\text{C}/\text{W}$
Operating and Storage Temperature Range	$T_J, T_{stg}$	-65 to +150	$^{\circ}\text{C}$
Maximum Temperature for Soldering Purposes, Time in Solder Bath	$T_L$	260 10	$^{\circ}\text{C}$ Sec

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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### OFF CHARACTERISTICS

Collector-Base Cutoff Current ( $V_{CB} = 50\text{ V}, I_E = 0$ )	$I_{CBO}$	-	-	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CE} = 50\text{ V}, I_B = 0$ )	$I_{CEO}$	-	-	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0\text{ V}, I_C = 0$ )	$I_{EBO}$	-	-	0.5	mAdc
	MMUN2211LT1	-	-	0.2	
	MMUN2212LT1	-	-	0.1	
	MMUN2213LT1	-	-	0.2	
	MMUN2214LT1	-	-	0.9	
	MMUN2215LT1	-	-	1.9	
	MMUN2216LT1	-	-	4.3	
	MMUN2230LT1	-	-	2.3	
	MMUN2231LT1	-	-	1.5	
	MMUN2232LT1	-	-	0.18	
	MMUN2233LT1	-	-	0.13	
	MMUN2234LT1	-	-	4.0	
	MMUN2238LT1	-	-	0.1	
	MMUN2241LT1	-	-		
Collector-Base Breakdown Voltage ( $I_C = 10\ \mu\text{A}, I_E = 0$ )	$V_{(BR)CBO}$	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (Note 2), ( $I_C = 2.0\text{ mA}, I_B = 0$ )	$V_{(BR)CEO}$	50	-	-	Vdc

### ON CHARACTERISTICS (Note 2)

DC Current Gain ( $V_{CE} = 10\text{ V}, I_C = 5.0\text{ mA}$ )	$h_{FE}$	35	60	-	
	MMUN2211LT1	60	100	-	
	MMUN2212LT1	80	140	-	
	MMUN2213LT1	80	140	-	
	MMUN2214LT1	160	350	-	
	MMUN2215LT1	160	350	-	
	MMUN2216LT1	3.0	5.0	-	
	MMUN2230LT1	8.0	15	-	
	MMUN2231LT1	15	30	-	
	MMUN2232LT1	80	200	-	
	MMUN2233LT1	80	150	-	
	MMUN2234LT1	160	350	-	
	MMUN2238LT1	160	350	-	
	MMUN2241LT1				
Collector-Emitter Saturation Voltage ( $I_C = 10\text{ mA}, I_B = 0.3\text{ mA}$ ) ( $I_C = 10\text{ mA}, I_B = 5\text{ mA}$ ) MMUN2230LT1/MMUN2231LT1 ( $I_C = 10\text{ mA}, I_B = 1\text{ mA}$ ) MMUN2215LT1/MMUN2216LT1 MMUN2232LT1/MMUN2233LT1/MMUN2234LT1/ MMUN2238LT1	$V_{CE(sat)}$	-	-	0.25	Vdc

2. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%.

## MMUN2211LT1 Series

### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit	
<b>ON CHARACTERISTICS</b> (Note 3)						
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 2.5 V, R <sub>L</sub> = 1.0 k Ω)	MMUN2211LT1 MMUN2212LT1 MMUN2214LT1 MMUN2215LT1 MMUN2216LT1 MMUN2230LT1 MMUN2231LT1 MMUN2232LT1 MMUN2233LT1 MMUN2234LT1 MMUN2238LT1 (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 3.5 V, R <sub>L</sub> = 1.0 k Ω) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 5.0 V, R <sub>L</sub> = 1.0 k Ω)	V <sub>OL</sub>	-	-	0.2	Vdc
Output Voltage (off) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.5 V, R <sub>L</sub> = 1.0 k Ω) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.050 V, R <sub>L</sub> = 1.0 k Ω) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.25 V, R <sub>L</sub> = 1.0 k Ω)	MMUN2230LT1 MMUN2215LT1 MMUN2216LT1 MMUN2233LT1 MMUN2238LT1	V <sub>OH</sub>	4.9	-	-	Vdc
Input Resistor	MMUN2211LT1 MMUN2212LT1 MMUN2213LT1 MMUN2214LT1 MMUN2215LT1 MMUN2216LT1 MMUN2230LT1 MMUN2231LT1 MMUN2232LT1 MMUN2233LT1 MMUN2234LT1 MMUN2238LT1 MMUN2241LT1	R1	7.0 15.4 32.9 7.0 7.0 3.3 0.7 1.5 3.3 3.3 15.4 1.54 70	10 22 47 10 10 4.7 1.0 2.2 4.7 4.7 22 2.2 100	13 28.6 61.1 13 13 6.1 1.3 2.9 6.1 6.1 28.6 2.88 130	kΩ
Resistor Ratio	MMUN2211LT1/MMUN2212LT1/MMUN2213LT1 MMUN2214LT1 MMUN2215LT1/MMUN2216LT1/MMUN2238LT1 MMUN2241LT1 MMUN2230LT1/MMUN2231LT1/MMUN2232LT1 MMUN2233LT1 MMUN2234LT1	R1/R2	0.8 0.17 - - 0.8 0.055 0.38	1.0 0.21 - - 1.0 0.1 0.47	1.2 0.25 - - 1.2 0.185 0.56	

3. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%.

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2211LT1

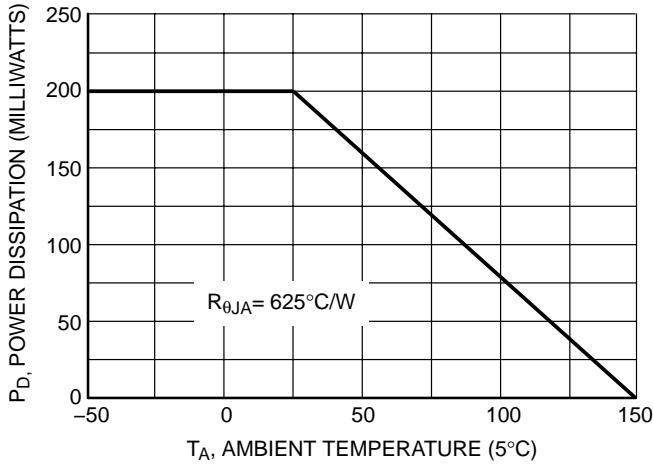


Figure 1. Derating Curve

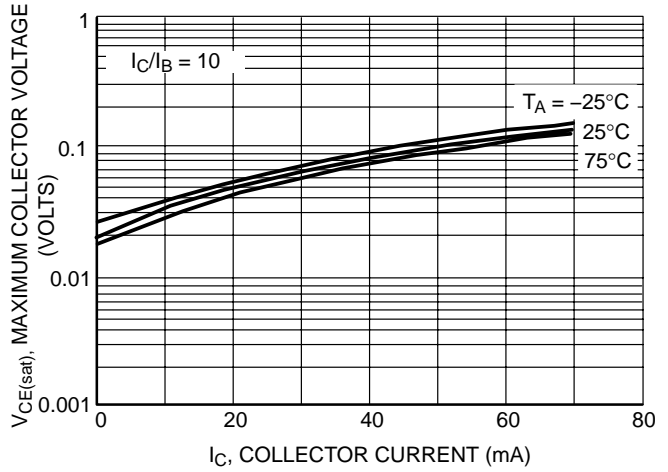


Figure 2. V<sub>CE(sat)</sub> vs. I<sub>C</sub>

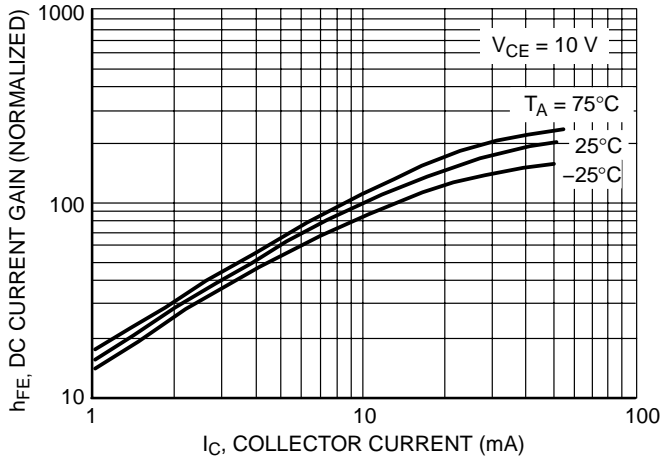


Figure 3. DC Current Gain

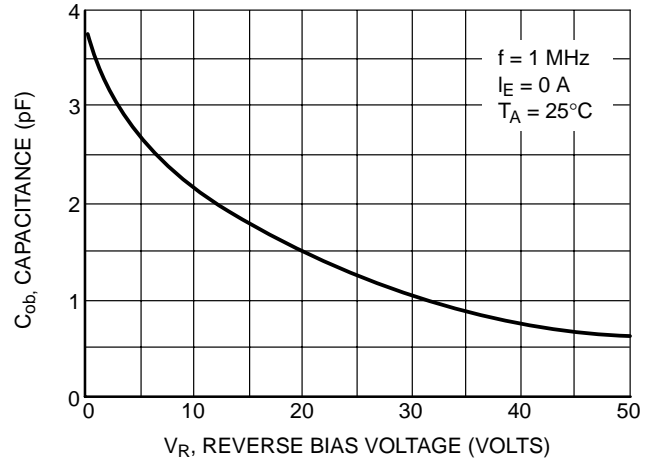


Figure 4. Output Capacitance

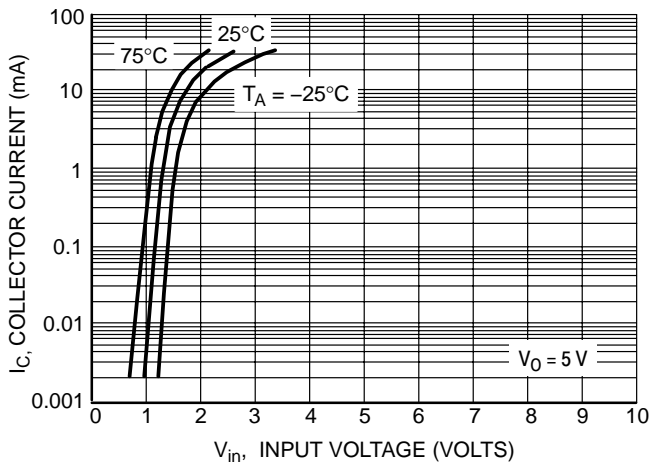


Figure 5. Output Current vs. Input Voltage

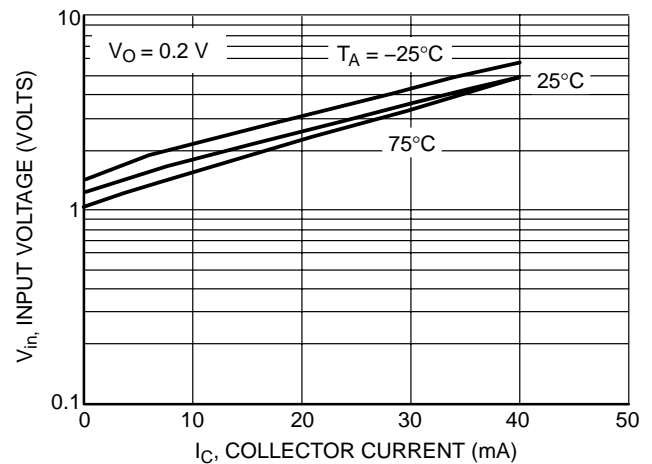


Figure 6. Input Voltage vs. Output Current

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2212LT1

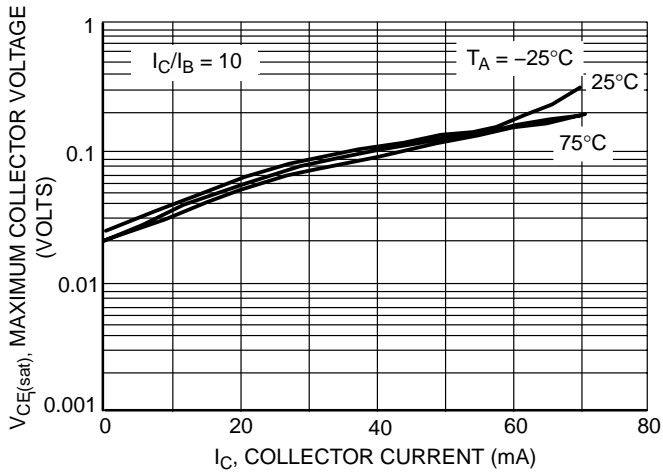


Figure 7.  $V_{CE(sat)}$  vs.  $I_C$

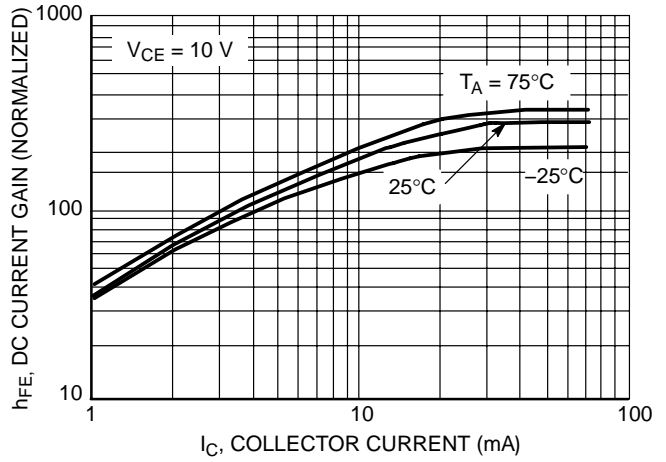


Figure 8. DC Current Gain

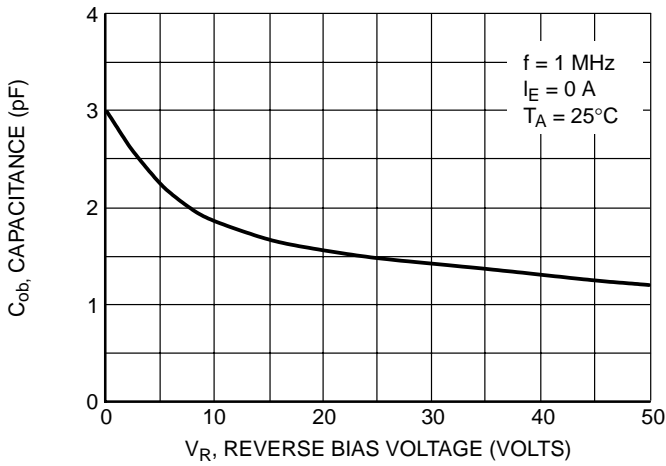


Figure 9. Output Capacitance

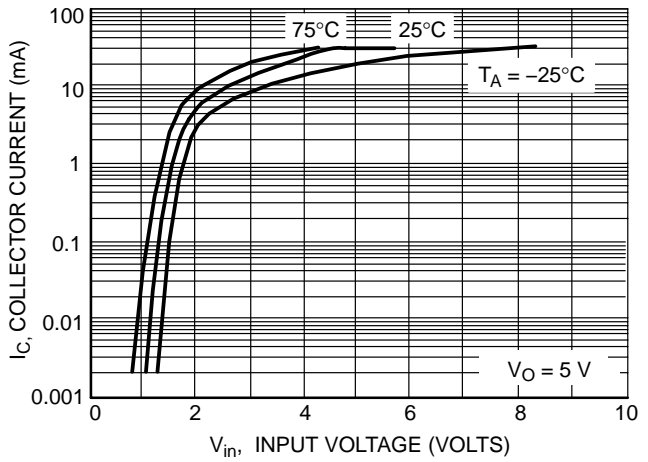


Figure 10. Output Current vs. Input Voltage

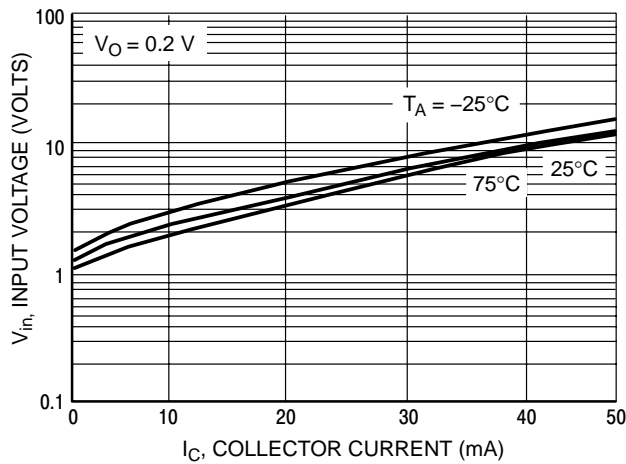


Figure 11. Input Voltage vs. Output Current

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2213LT1

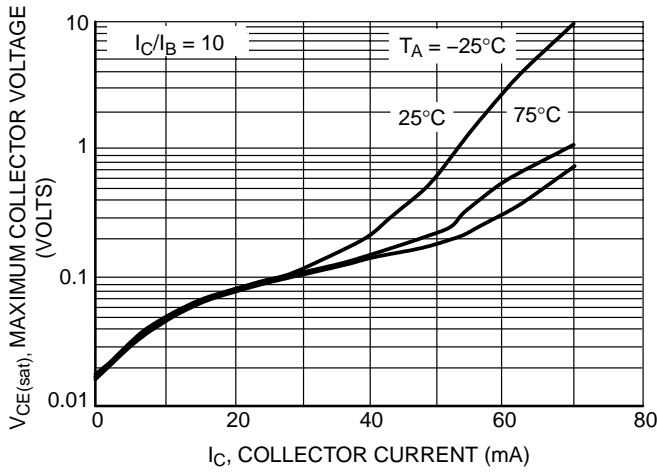


Figure 12.  $V_{CE(sat)}$  vs.  $I_C$

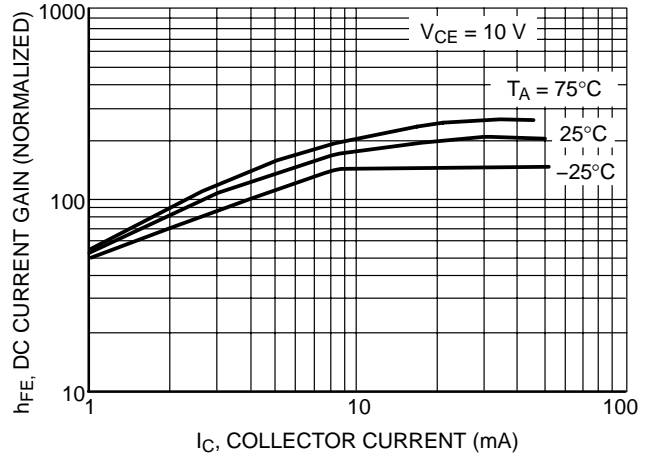


Figure 13. DC Current Gain

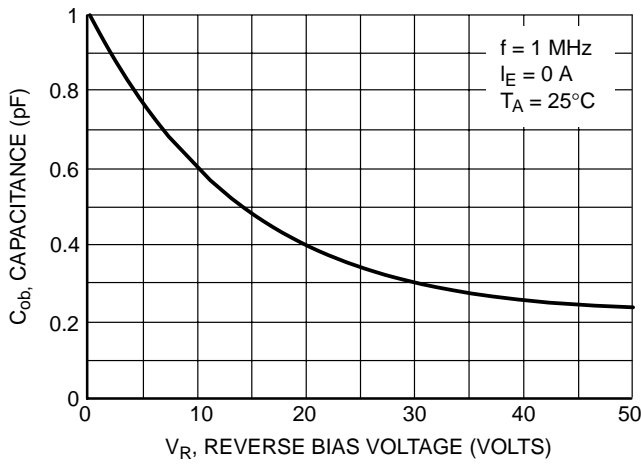


Figure 14. Output Capacitance

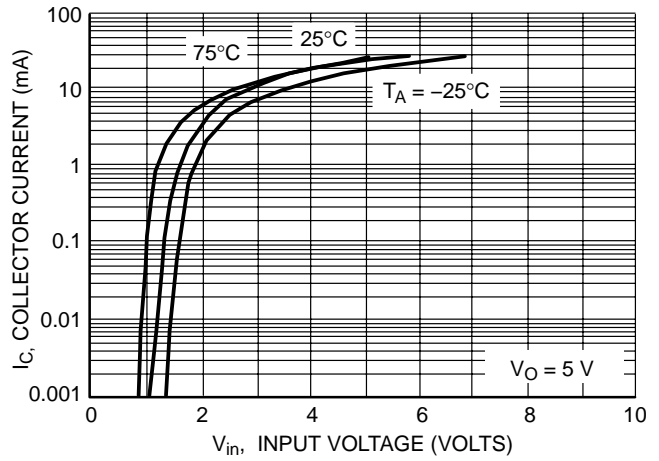


Figure 15. Output Current vs. Input Voltage

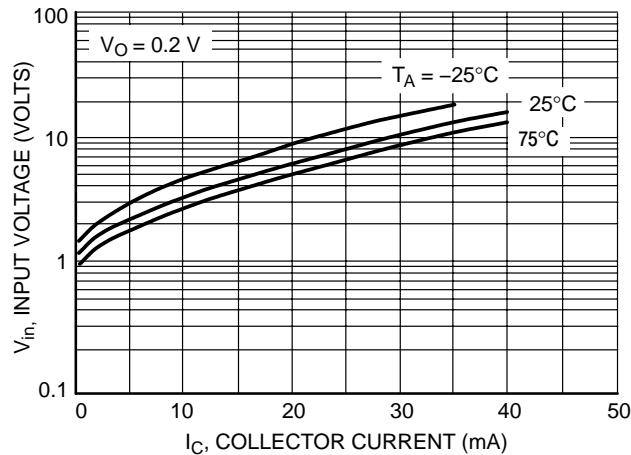


Figure 16. Input Voltage vs. Output Current

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2214LT1

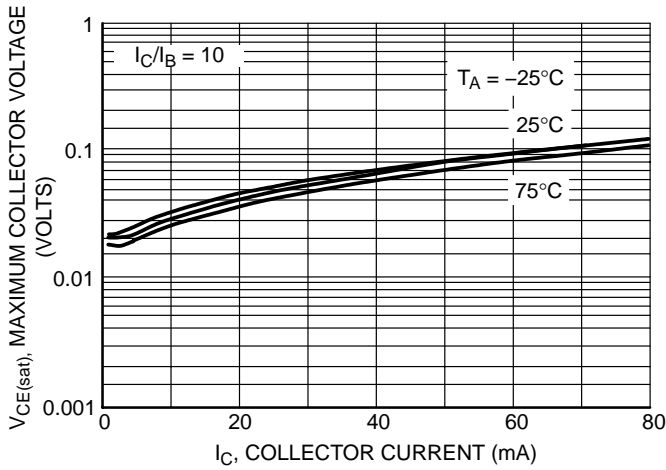


Figure 17.  $V_{CE(sat)}$  vs.  $I_C$

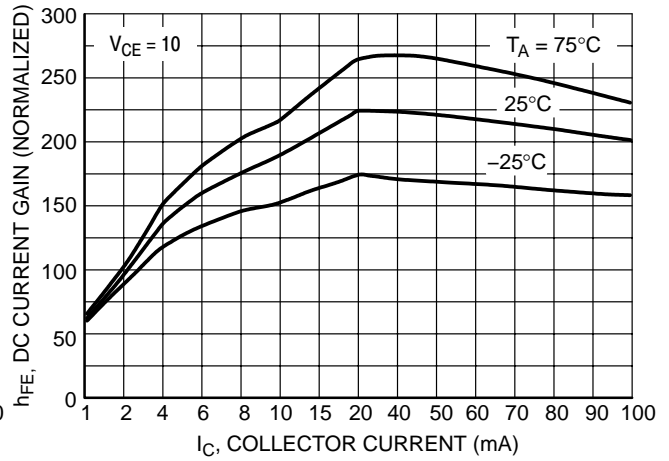


Figure 18. DC Current Gain

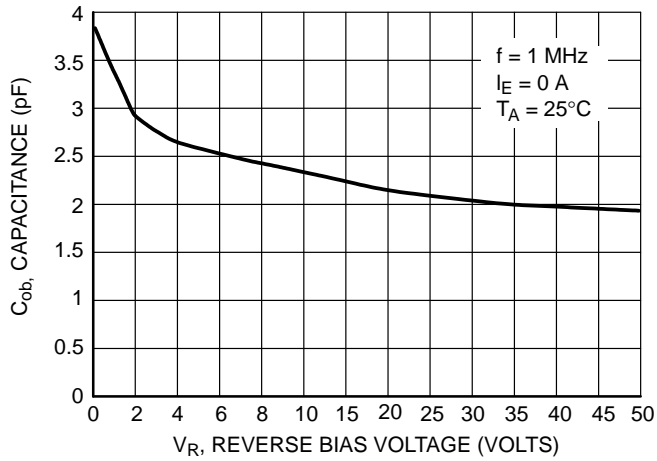


Figure 19. Output Capacitance

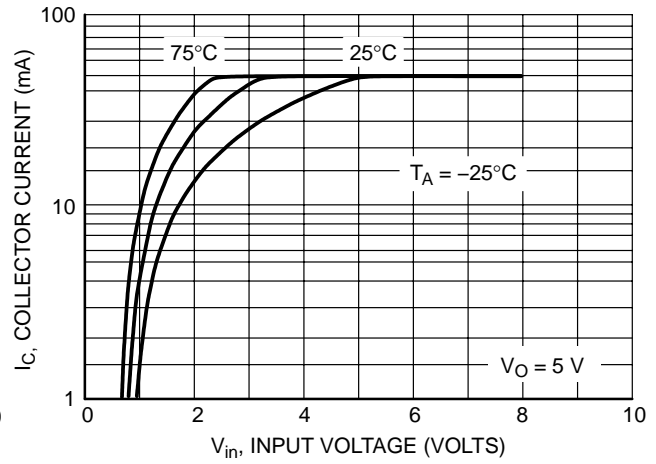


Figure 20. Output Current vs. Input Voltage

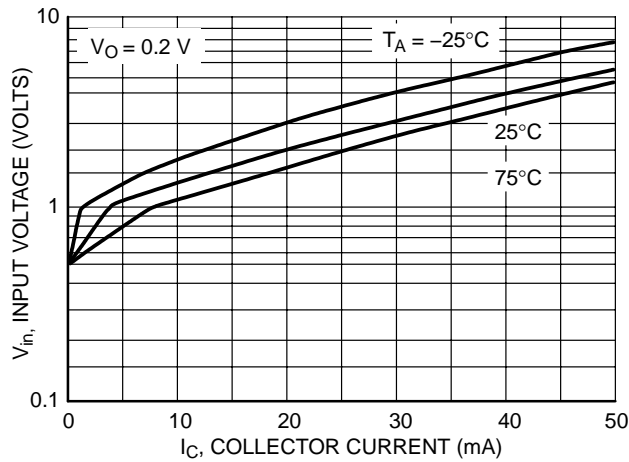


Figure 21. Input Voltage vs. Output Current

# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2232LT1

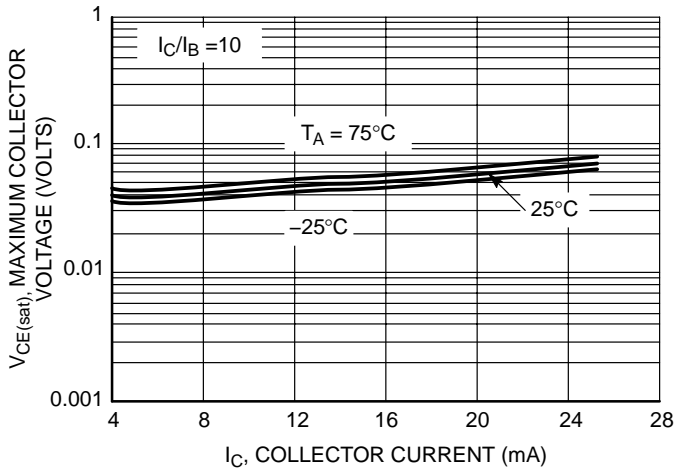


Figure 22.  $V_{CE(sat)}$  vs.  $I_C$

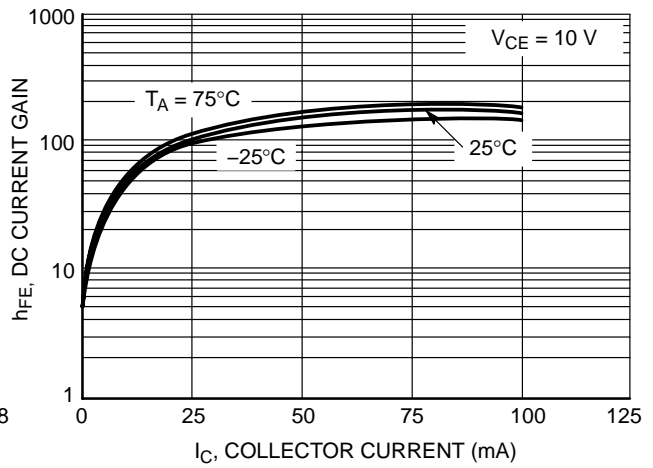


Figure 23. DC Current Gain

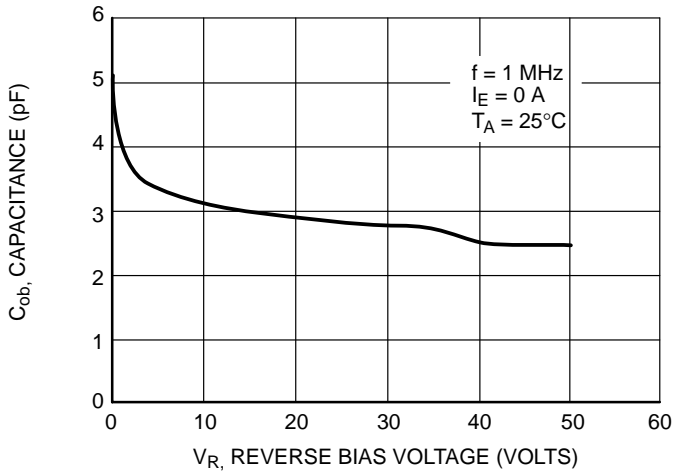


Figure 24. Output Capacitance

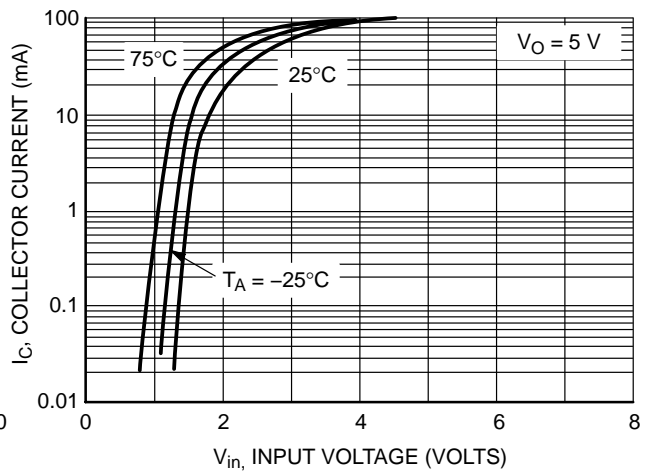


Figure 25. Output Current vs. Input Voltage

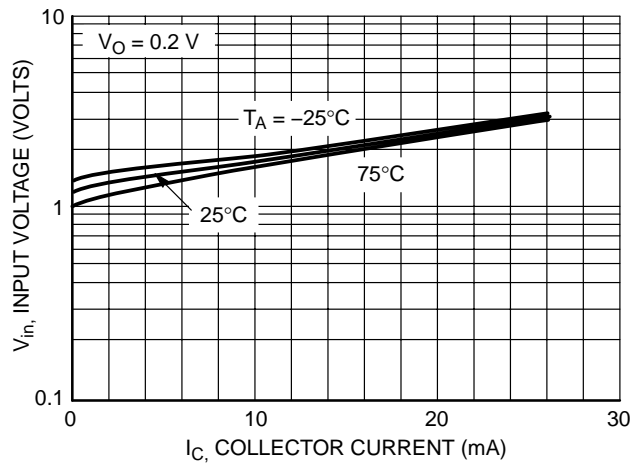


Figure 26. Output Voltage vs. Input Current



# MMUN2211LT1 Series

## TYPICAL ELECTRICAL CHARACTERISTICS MMUN2233LT1

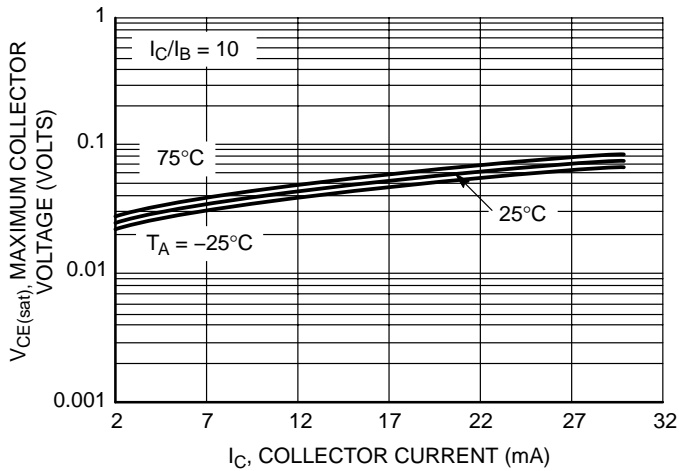


Figure 27.  $V_{CE(sat)}$  vs.  $I_C$

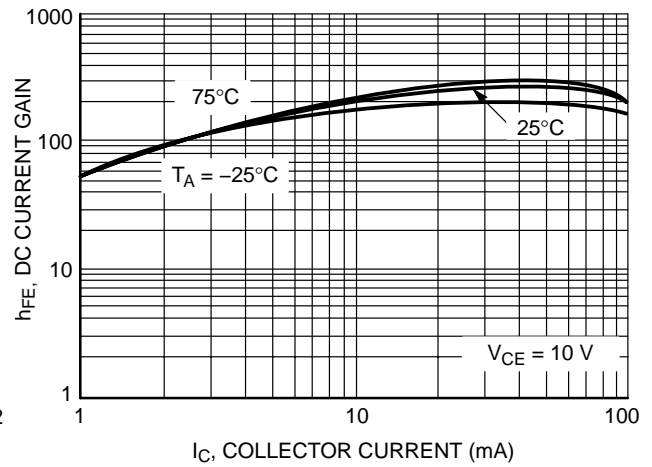


Figure 28. DC Current Gain

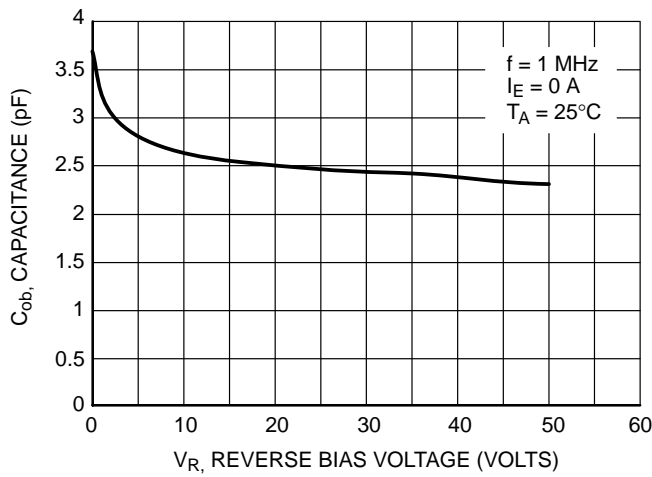


Figure 29. Output Capacitance

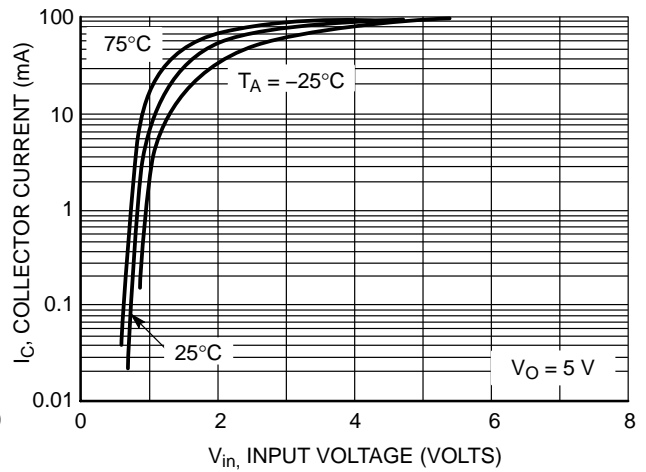


Figure 30. Output Current vs. Input Voltage

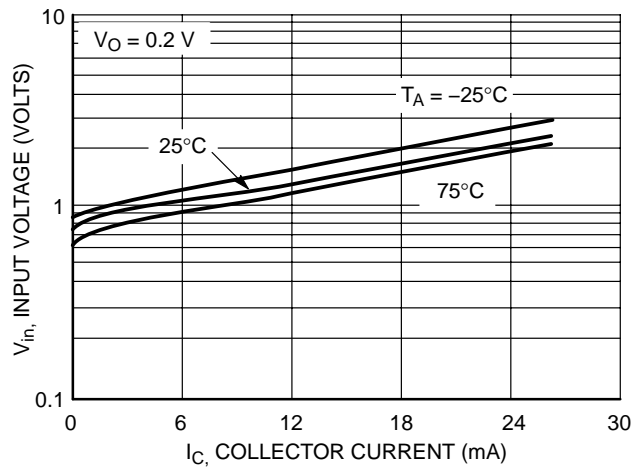


Figure 31. Input Voltage vs. Output Current

# MMUN2211LT1 Series

## TYPICAL APPLICATIONS FOR NPN BRTs

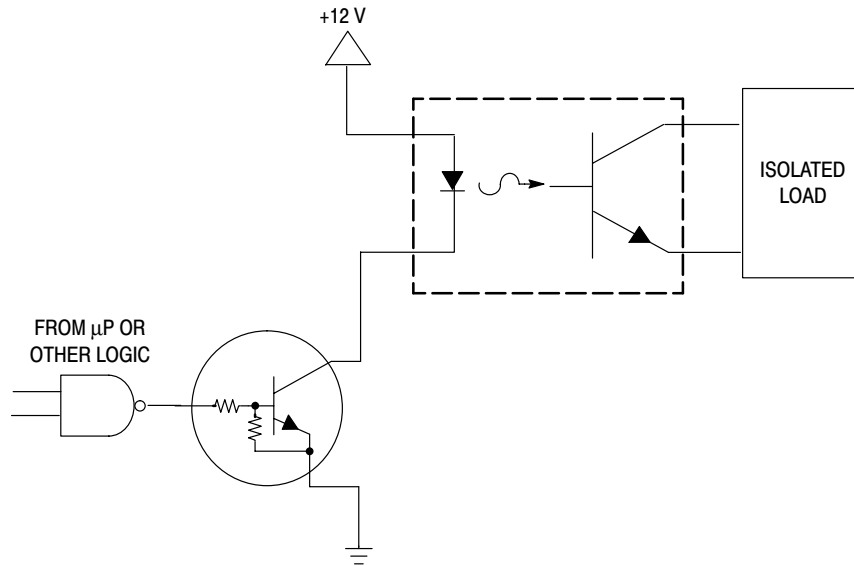


Figure 32. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

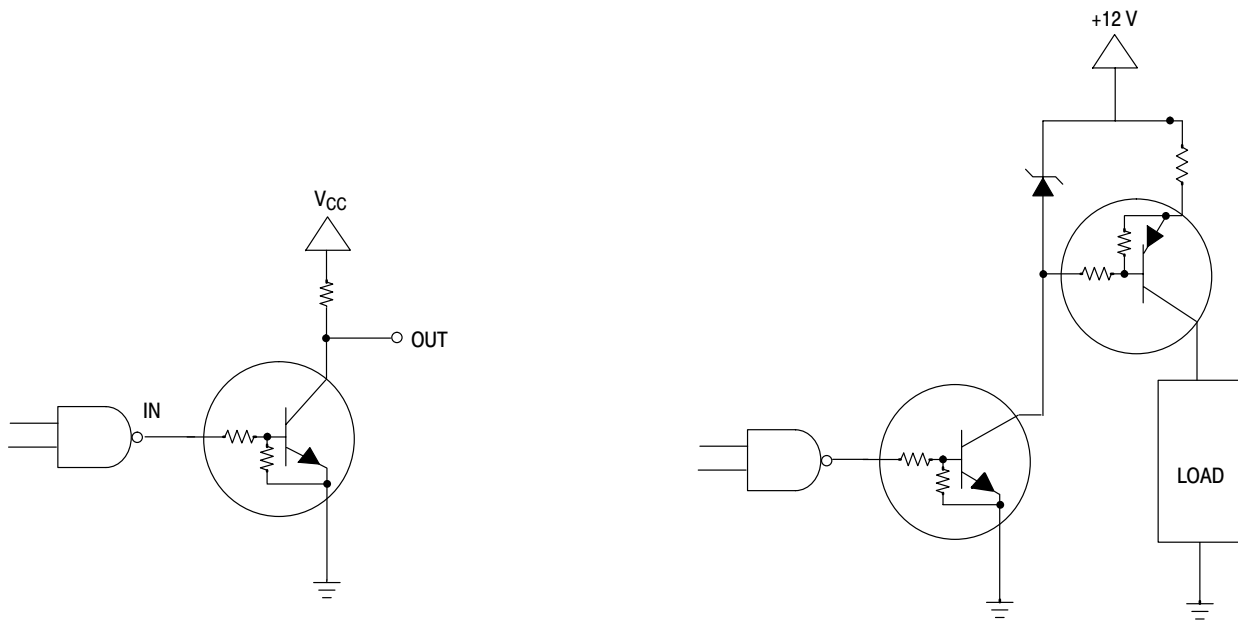


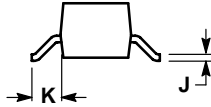
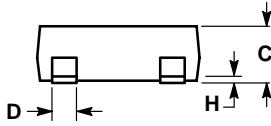
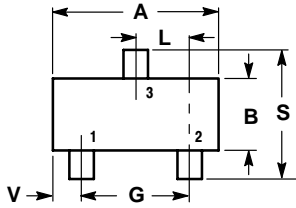
Figure 33. Open Collector Inverter: Inverts the Input Signal

Figure 34. Inexpensive, Unregulated Current Source

# MMUN2211LT1 Series

## PACKAGE DIMENSIONS

SOT-23  
TO-236AB  
CASE 318-08  
ISSUE AI



NOTES:

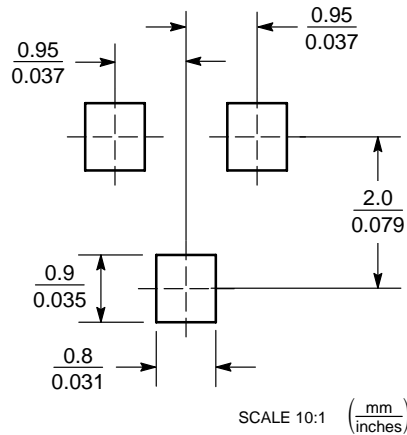
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-03 AND -07 OBSOLETE, NEW STANDARD 318-08.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

STYLE 6:

1. BASE
2. EMITTER
3. COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MMUN2211LT1 Series

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